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APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/772,082		02/04/2004	Hiroyuki Uwazumi	FUJI:289	2572	
37013	7590	09/11/2006		EXAMINER		
•		& McDOWELL LLP	RICKMAN, HOLLY C			
	P.O. BOX 826 ASHBURN, VA 20146-0826			ART UNIT	PAPER NUMBER	
,				1773		
				DATE MAILED: 09/11/2006		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)					
	Office Action Commons	10/772,082	UWAZUMI ET AL.					
	Office Action Summary	Examiner	Art Unit					
		Holly Rickman	1773					
Period fo	The MAILING DATE of this communication ap or Reply	ppears on the cover sheet with the	correspondence address					
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLICHEVER IS LONGER, FROM THE MAILING Insions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. In period for reply is specified above, the maximum statutory period re to reply within the set or extended period for reply will, by statutely received by the Office later than three months after the mailined patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICATIO .136(a). In no event, however, may a reply be tid d will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONI	N. mely filed n the mailing date of this communication. ED (35 U.S.C. § 133).					
Status								
1)⊠	Responsive to communication(s) filed on 6/22	2/06.						
′=	This action is FINAL . 2b) ☐ This action is non-final.							
3)□								
,—	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Disposit	on of Claims							
4)⊠	4)⊠ Claim(s) <u>1-34</u> is/are pending in the application.							
	4a) Of the above claim(s) <u>16-34</u> is/are withdrawn from consideration.							
5)[Claim(s) is/are allowed.							
6)⊠	Claim(s) <u>1-15</u> is/are rejected.							
7)	Claim(s) is/are objected to.							
8)□	B) Claim(s) are subject to restriction and/or election requirement.							
Applicati	on Papers							
9)[The specification is objected to by the Examin	er.						
10)	10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11)	The oath or declaration is objected to by the E	Examiner. Note the attached Office	e Action or form PTO-152.					
Priority ι	ınder 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of:								
	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
	3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.								
•	see the attached detailed Office action for a lis	a of the certified copies not receive	ea.					
Attachmen	t(s)							
1) 🛛 Notic	e of References Cited (PTO-892)	4) Interview Summar						
	e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08	Paper No(s)/Mail D	Date Patent Application (PTO-152)					
	r No(s)/Mail Date	6) Other:	+					

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-4 are rejected under 35 U.S.C. 102(b) as being anticipated by Patel et al. (US 4224381).

Patel et al. disclose a magnetic recording medium having a Al alloy substrate, a first magnetic NiP layer which contains 6 wt% of P corresponding to the claimed soft magnetic layer, and a non-magnetic NiP layer disposed thereon. The thickness of the magnetic NiP layer is as high as 20 micron (ie, 800 microinches) and the thickness of the non-magnetic NiP layer is between the claimed values of 0.5-7 microns (i.e. 80 microinches). See col. 3, lines 34-53; col. 6, lines 6-26.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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4. The rejection of claims 1-15 under 35 U.S.C. 103(a) as being unpatentable over Sakawa et al. (English translation of JP 07-066034) is withdrawn in view of Applicant's amendments.

5. Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over Patel et al. (US 4224381).

Patel et al. disclose a magnetic recording medium having a Al alloy substrate, a first magnetic NiP layer which contains 6 wt% of P corresponding to the claimed soft magnetic layer, and a non-magnetic NiP layer disposed thereon. The thickness of the magnetic NiP layer is as high as 20 micron (ie, 800 microinches) and the thickness of the non-magnetic NiP layer is between the claimed values of 0.5-7 microns (i.e. 80 microinches). See col. 3, lines 34-53; col. 6, lines 6-26. The reference teaches a range of 6-14 wt% P for the non-magnetic NiP layer. It would have been well within the level of ordinary skill in the art at the time of invention to choose an optimal value from within this range given the apparent equivalence of all values within the disclosed range.

6. Claims 6-7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Patel et al. (US 4224381) in view of Oshima (US 6818031).

Patel et al. disclose all of the limitations of the claims as detailed above, except for the required surface roughness and waviness of the soft magnetic NiP layer.

Oshima teaches that it is known in the art to polish a NiP plated substrate layer to have a roughness Ra of less than 0.25 nm and a waviness Wa of less than 0.25 nm. (col. 11, line 45 to

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col. 12, line 8). The reference teaches that the improved surface smoothness allows for increased areal density and reduced flying height (col. 1, line 15 to col. 2, line 8).

It would have been obvious to one of ordinary skill in the art at the time of invention to polish the surface of the NiP layer taught by Patel in accordance with the teaching of Oshima in order to produce a recording medium having reduced flying height and increased areal density.

7. Claims 8-12 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Patel et al. (US 4224381) in view of Wu et al. (US 6432562).

Patel et al. disclose all of the limitations of the claims as detailed above, except for the claimed structure of the seedlayer, perpendicular recording layer and protective layer deposited on the NiP/Al base layer disclosed therein. The reference teaches that the magnetic recording layer deposited on the NIP-coated Al base is not particularly limited (col. 6, lines 49-63).

Wu et al. teach a magnetic recording structure including a seedlayer, a perpendicular magnetic layer and a protective overcoat layer for deposition on an Al alloy substrate.

It would have been obvious to one of ordinary skill in the art to use the recording layer structure taught by Wu et al. in combination with the NiP-coated Al substrate structure taught by Patel et al. in order to achieve the benefits disclosed by Wu et al. such as high areal density and high magnetic performance such as high SNR.

8. Claims 13-14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Patel et al. (US 4224381) in view of Wu et al. (US 6432562) further in view of Oshima (US 6818031).

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Patel et al. in view of Wu et al. teach all of the limitations of the claims as detailed above, except for the required surface roughness and waviness of the soft magnetic NiP layer.

Oshima teaches that it is known in the art to polish a NiP plated substrate layer to have a roughness Ra of less than 0.25 nm and a waviness Wa of less than 0.25 nm. (col. 11, line 45 to col. 12, line 8). The reference teaches that the improved surface smoothness allows for increased areal density and reduced flying height (col. 1, line 15 to col. 2, line 8).

It would have been obvious to one of ordinary skill in the art at the time of invention to polish the surface of the NiP layer taught by Patel in accordance with the teaching of Oshima in order to produce a recording medium having reduced flying height and increased areal density.

Response to Arguments

- 9. Applicant's arguments filed 6/22/06 have been considered but are moot in view of the new ground(s) of rejection.
- 10. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37

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CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Holly Rickman whose telephone number is (571) 272-1514. The examiner can normally be reached on Monday-Friday 9:30-6:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carol Chaney can be reached on (571) 272-1284. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Holly Rickman Primary Examiner Art Unit 1773